



CORNERSTONE Device Dimensions for 220 nm SOI Platform

Grating etch depth = 70 nm



TE mode
 $\lambda = 1550 \text{ nm}$

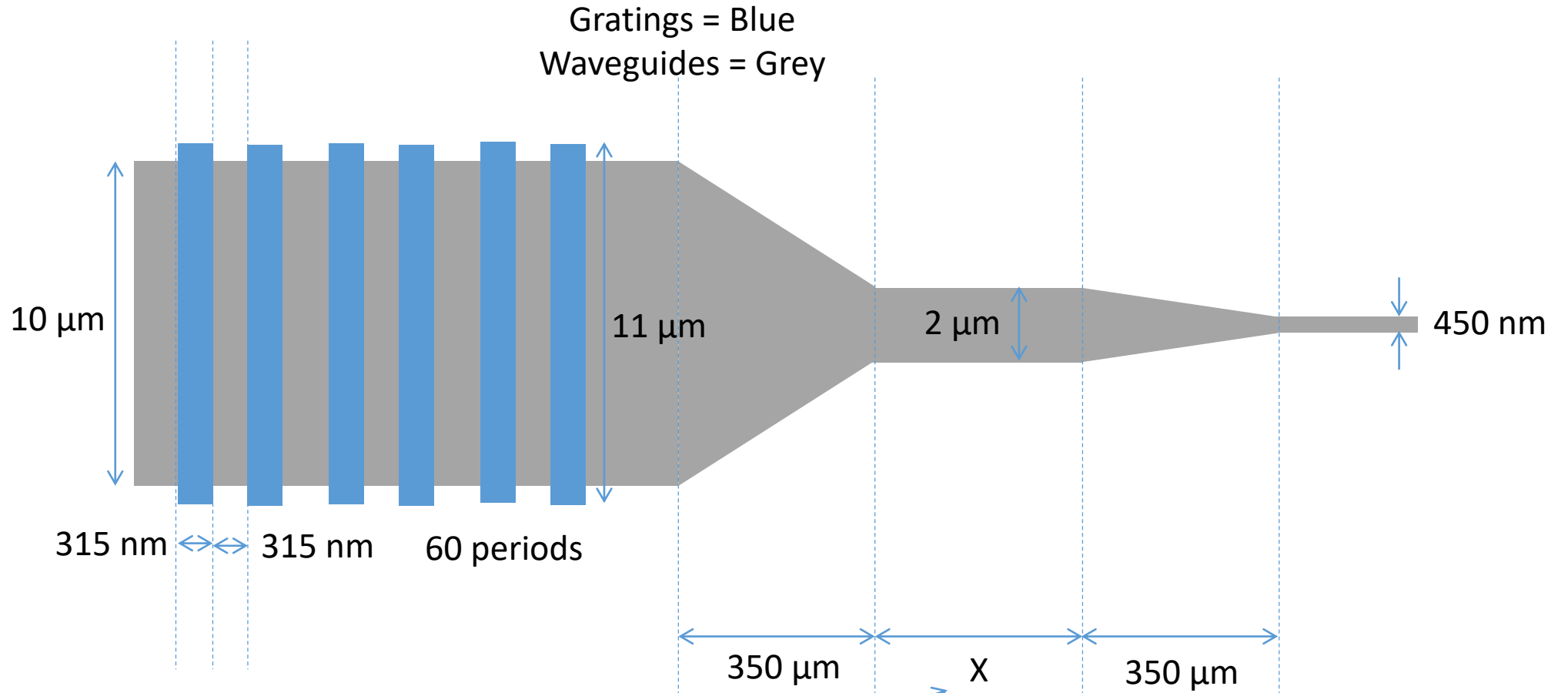
Grating etch depth = 70 nm



TE single mode waveguides and bends

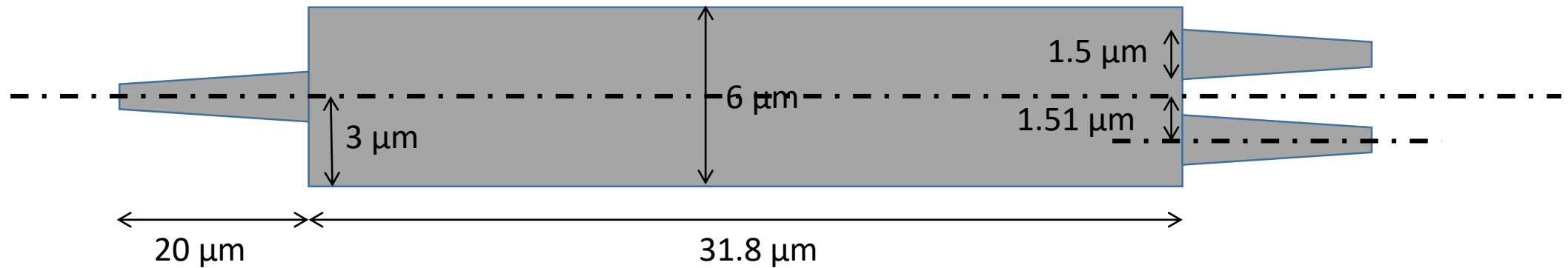
Property	Wavelength = 1550 nm
<u>Strip waveguides</u>	
Maximum single mode waveguide width (nm)	450
Minimum bend radius (width = 450 nm) (μm)	5

TE grating coupler (etch depth = 70 nm)

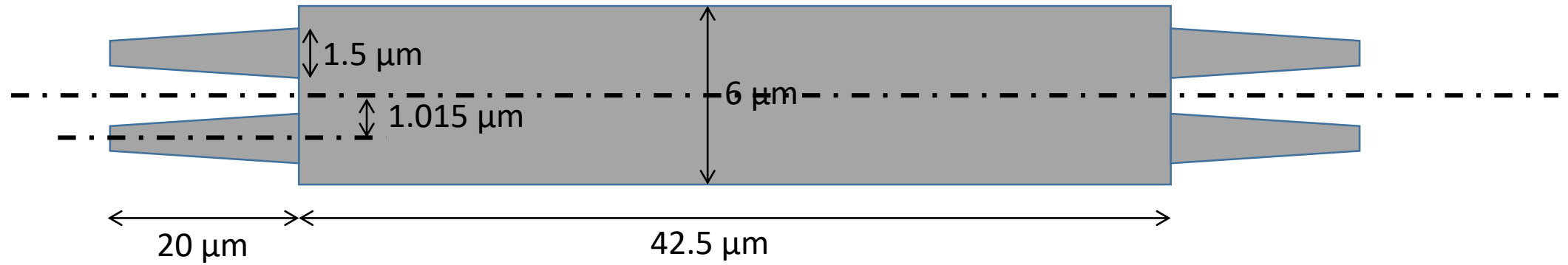


Use waveguide of width X for low loss routing to devices if required

TE 1x2 MMI STRIP dimensions



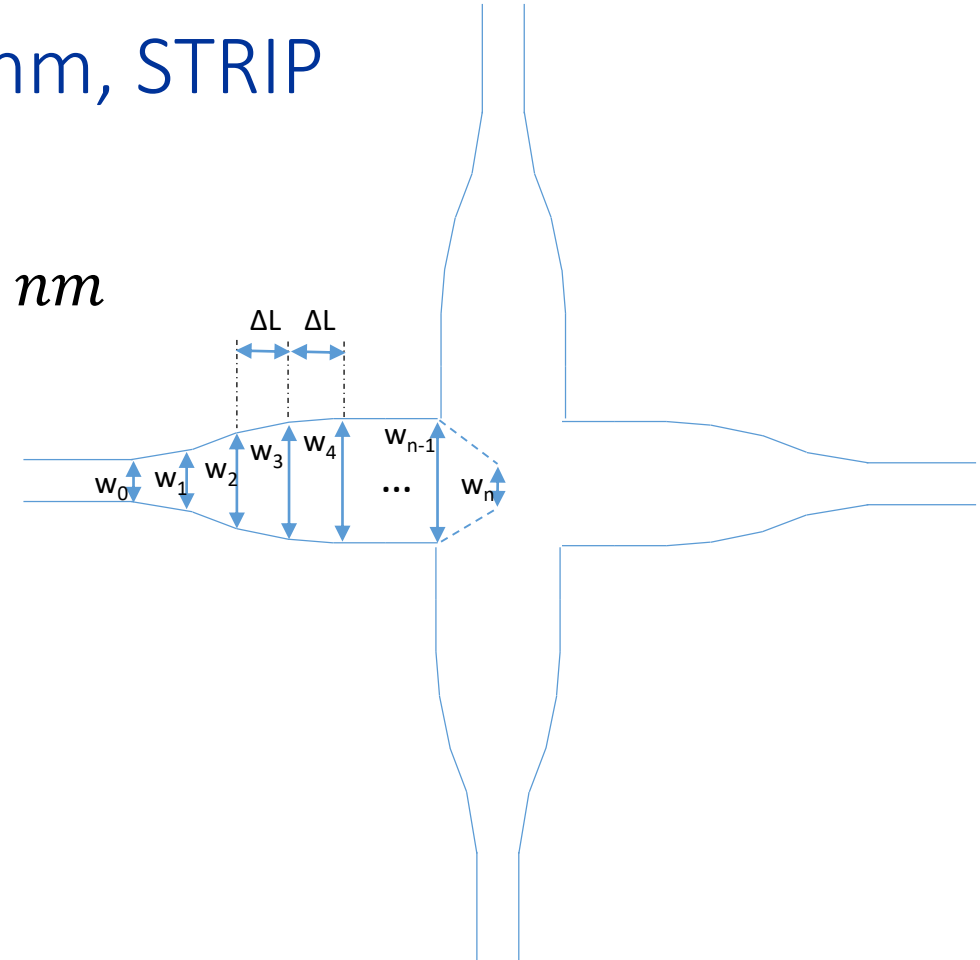
TE 2x2 MMI STRIP dimensions



Width point	Width (um)
w0	Waveguide width
w1	0.439
w2	0.6
w3	1.20
w4	1.334
w5	1.370
w6	1.418
W7	1.6
W8	1.589
W9	1.848
W10	1.855
W11	1.85
W12	Waveguide width (doesn't affect)

$\lambda = 1550 \text{ nm}$, STRIP

$\Delta L = 0.385 \text{ nm}$





TE mode
 $\lambda = 1310 \text{ nm}$

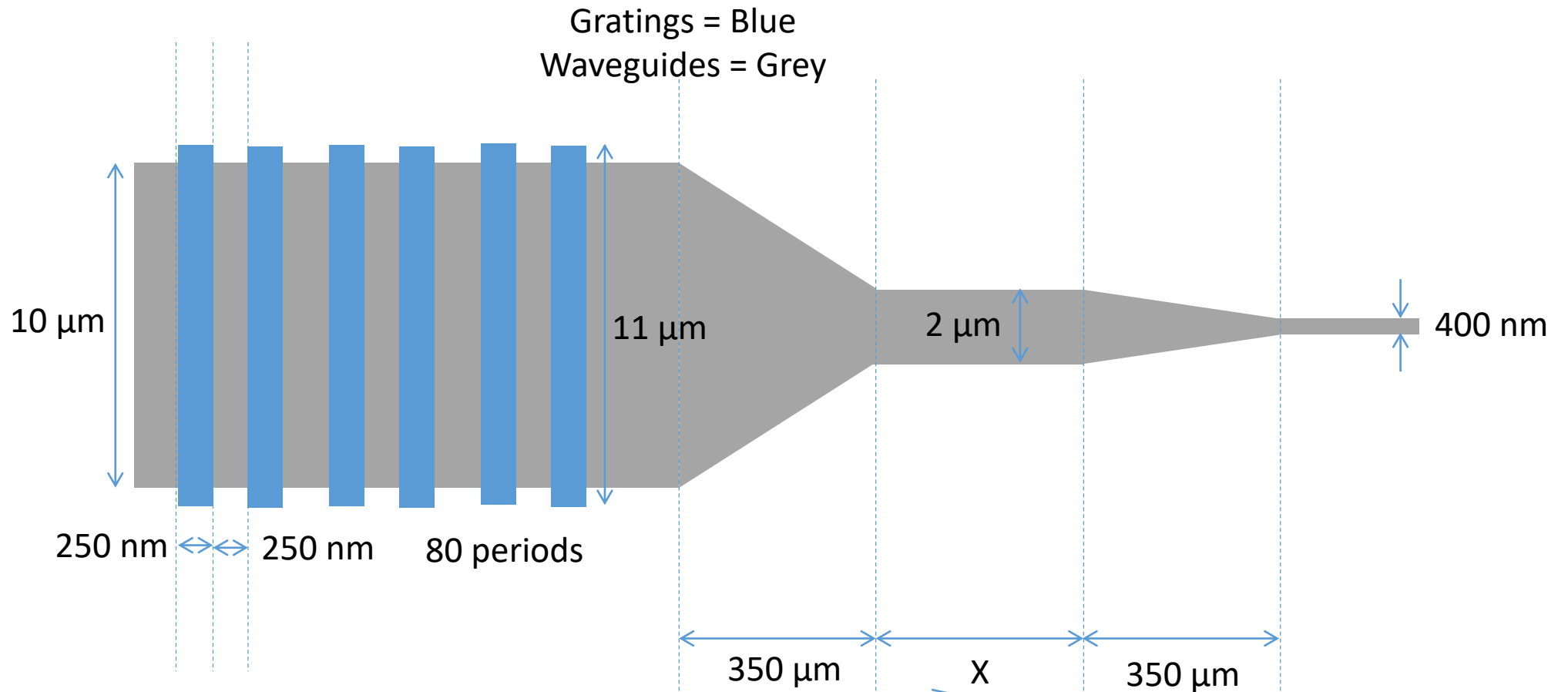
Grating etch depth = 70 nm



TE single mode waveguides and bends

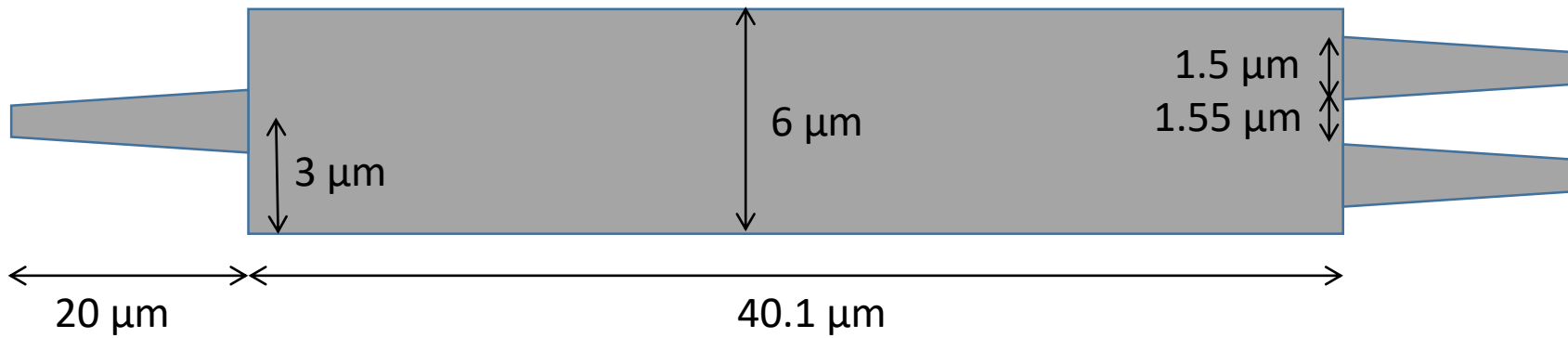
Property	Wavelength = 1310 nm
<u>Strip waveguides</u>	
Maximum single mode waveguide width (nm)	400
Minimum bend radius (width = 400 nm) (μm)	5

TE grating coupler (etch depth = 70 nm)

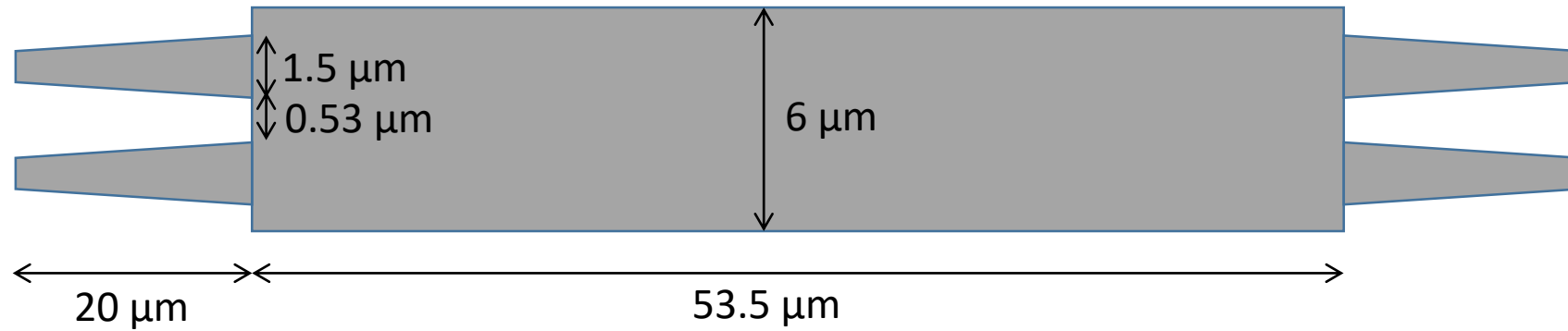


Use waveguide of width X for low loss routing to devices if required

TE 1x2 STRIP MMI dimensions



TE 2x2 STRIP MMI dimensions



Width point	Width (um)
w0	Waveguide width
w1	0.6
w2	1.2
w3	1.168
w4	1.168
w5	1.307
w6	1.428
w7	1.7
w8	1.85
w9	2.0
w10	1.85
w11	Waveguide width (doesn't affect)

$\lambda = 1310 \text{ nm}$, STRIP

$\Delta L = 0.385 \text{ nm}$

